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**Product data sheet** 

## 1. General description

NPN/NPN Resistor-Equipped double Transistors (RET) in an ultra small DFN1412-6 (SOT1268) leadless Surface-Mounted Device (SMD) plastic package.

PNP/PNP complement: PRMB11. NPN/PNP complement: PRMD3.

#### 2. Features and benefits

- 100 mA output current capability
- · Built-in bias resistors
- · Simplifies circuit design
- · Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- AEC-Q101 qualified

## 3. Applications

- Digital applications
- Cost-saving alternative to BC847/BC857 series in digital applications
- · Control of IC inputs
- Switching loads

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit		
Per transiste	Per transistor								
$V_{CEO}$	collector-emitter voltage	open base		-	-	50	V		
Io	output current			-	-	100	mA		
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_{C}$ = 5 mA; $T_{amb}$ = 25 °C		30	-	-			
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ		
R2/R1	bias resistor ratio		[1]	0.8	1	1.2			

[1] See section "Test information" for resistor calculation and test conditions.



50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

# 5. Pinning information

#### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	GND1	GND (emitter) TR1		6 5 4
2	I1	input (base) TR1	7 6	
3	O2	output (collector) TR2	2 5	R1 R2
4	GND2	GND (emitter) TR2		TR1
5	12	input (base) TR2	3 4	R2 R1
6	01	output (collector) TR1	Transparent top view	
7	01	output (collector) TR1	DFN1412-6 (SOT1268)	1 2 3
8	O2	output (collector) TR2	, ,	sym063

## **6. Ordering information**

#### **Table 3. Ordering information**

Type number	Package	ackage				
	Name	Description	Version			
PRMH11	DFN1412-6	plastic thermal enhanced ultra thin small outline package; no leads; 6 terminals; body: 1.4 mm x 1.2 mm x 0.47 mm	SOT1268			

# 7. Marking

### **Table 4. Marking codes**

Type number	Marking code
PRMH11	В9

50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

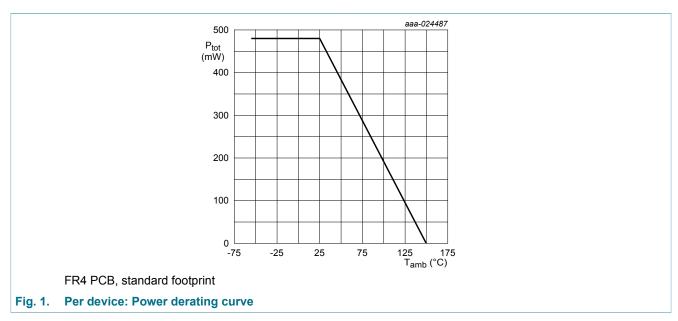
# 8. Limiting values

**Table 5. Limiting values** 

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or					'
V <sub>CBO</sub>	collector-base voltage	open emitter		-	50	V
$V_{CEO}$	collector-emitter voltage	open base		-	50	V
V <sub>EBO</sub>	emitter-base voltage	open collector		-	10	V
V <sub>I</sub>	input voltage	positive		-	40	V
		negative		-	-10	V
lo	output current			-	100	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	325	mW
Per device	'			'		'
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C	[1]	-	480	mW
Tj	junction temperature			-	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.



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#### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transis	tor			,		,	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	385	K/W
Per device				,		,	,
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	261	K/W

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

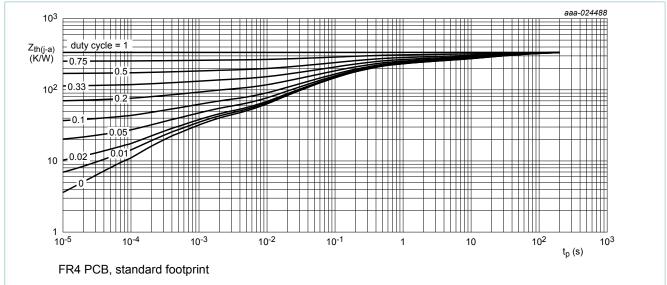


Fig. 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

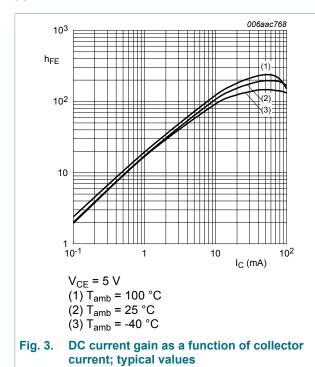
## 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

### 10. Characteristics

**Table 7. Characteristics** 

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or						
I <sub>CBO</sub>	collector-base cut-off current (emitter open)	$V_{CB} = 50 \text{ V}; I_{E} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	100	nA
I <sub>CEO</sub>	collector-emitter cut-off	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>amb</sub> = 25 °C		-	-	1	μΑ
	current (base open)	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0 A; T <sub>j</sub> = 150 °C		-	-	5	μΑ
I <sub>EBO</sub>	emitter-base cut-off current (collector open)	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$		-	-	400	μA
h <sub>FE</sub>	DC current gain	$V_{CE}$ = 5 V; $I_{C}$ = 5 mA; $T_{amb}$ = 25 °C		30	-	-	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}; T_{amb} = 25 \text{ °C}$		-	-	150	mV
$V_{I(off)}$	off-state input voltage	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 100 μA; T <sub>amb</sub> = 25 °C		-	1.1	8.0	V
V <sub>I(on)</sub>	on-state input voltage	$V_{CE}$ = 0.3 V; $I_{C}$ = 10 mA; $T_{amb}$ = 25 °C		2.5	1.8	-	V
R1	bias resistor 1	T <sub>amb</sub> = 25 °C	[1]	7	10	13	kΩ
R2/R1	bias resistor ratio		[1]	0.8	1	1.2	
C <sub>C</sub>	collector capacitance	V <sub>CB</sub> = 10 V; I <sub>E</sub> = 0 A; i <sub>e</sub> = 0 A; f = 1 MHz; T <sub>amb</sub> = 25 °C		-	-	2.5	pF
f <sub>T</sub>	transition frequency	$V_{CE}$ = 5 V; $I_{C}$ = 10 mA; f = 100 MHz; $T_{amb}$ = 25 °C	[2]	-	230	-	MHz

- [1] See section "Test information" for resistor calculation and test conditions.
- [2] Characteristics of built-in transistor



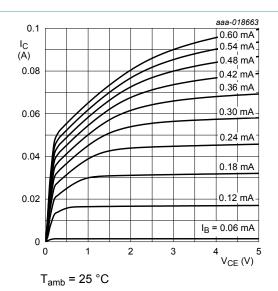


Fig. 4. Collector current as a function of collectoremitter voltage; typical values

#### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

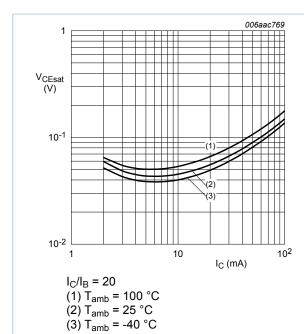
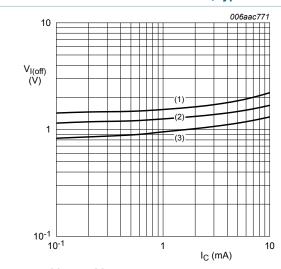


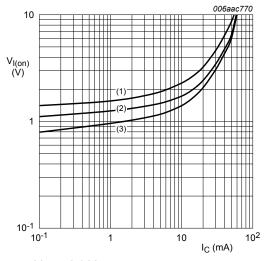
Fig. 5. Collector-emitter saturation voltage as a function of collector current; typical values



 $V_{CE} = 5 V$ (1)  $T_{amb} = -40 \,^{\circ}C$ 

(2) T<sub>amb</sub> = 25 °C (3) T<sub>amb</sub> = 100 °C

Fig. 7. Off-state input voltage as a function of collector current; typical values



 $V_{CE} = 0.3 \text{ V}$ (1)  $T_{amb} = -40 \text{ °C}$ (2)  $T_{amb} = 25 \text{ °C}$ (3)  $T_{amb} = 100 \text{ °C}$ 

Fig. 6. On-state input voltage as a function of collector current; typical values

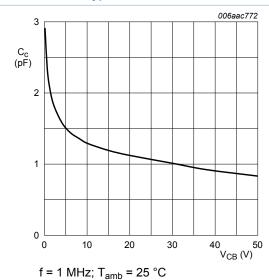
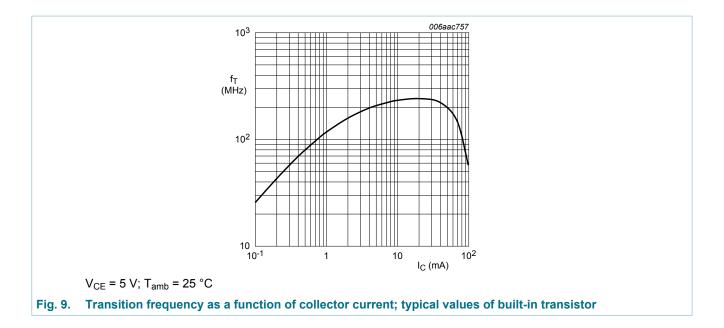


Fig. 8. Collector capacitance as a function of collector-base voltage; typical values

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#### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

### 11. Test information

### **Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

#### **Resistor calculation**

· Calculation of bias resistor 1 (R1)

$$RI = \frac{V(I12) - V(I11)}{I12 - I11}$$

Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

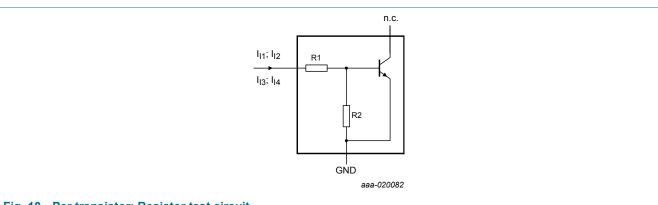


Fig. 10. Per transistor: Resistor test circuit

#### **Resistor test conditions**

**Table 8. Resistor test conditions** 

R1 (kΩ)	R2 (kΩ)	Test conditions			
		I <sub>I1</sub>	I <sub>I2</sub>	I <sub>13</sub>	I <sub>14</sub>
10	10	350 μΑ	450 µA	-350 µA	-450 μΑ

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## 12. Package outline

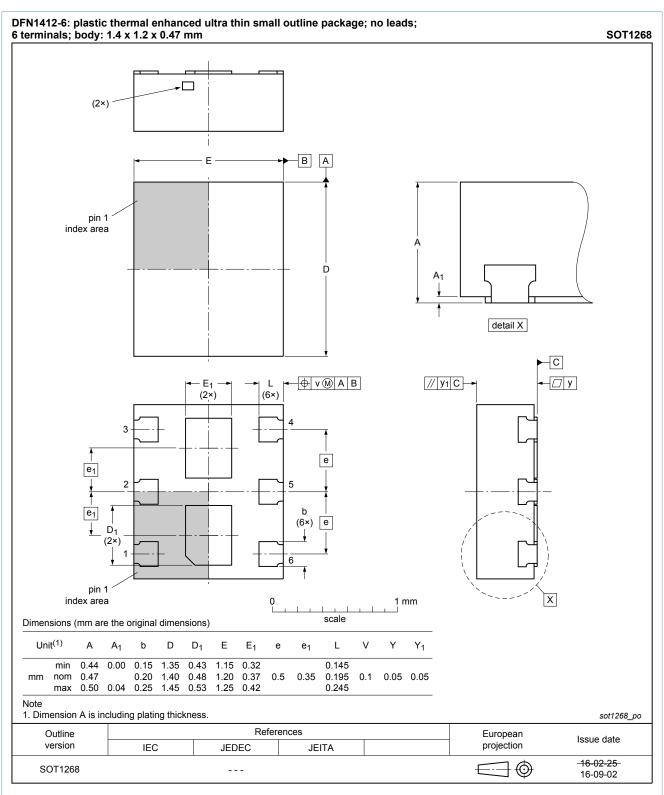
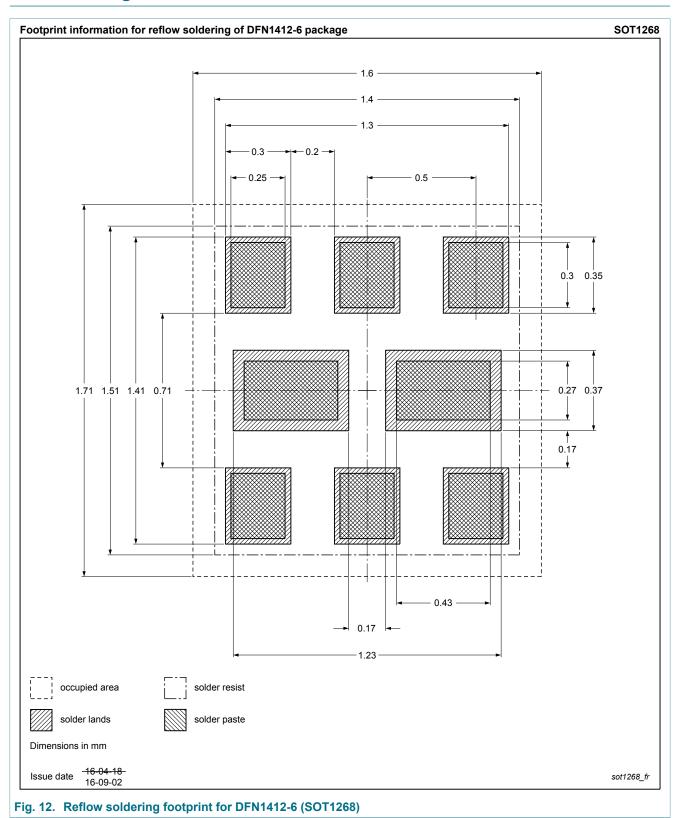


Fig. 11. Package outline DFN1412-6 (SOT1268)

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## 13. Soldering



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# 14. Revision history

### Table 9. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PRMH11 v.1	20170814	Product data sheet	-	-

#### 50 V, 100 mA NPN/NPN Resistor-Equipped double Transistors (RET)

## 15. Legal information

#### **Data sheet status**

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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